



# US1A - US1M

#### **1.0A SURFACE MOUNT ULTRA-FAST RECTIFIER**

## Features

- Glass Passivated Die Construction
- Ultra-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 30A Peak
- High Current Capability
- Ideally Suited for Automated Assembly
- Lead-Free Finish; RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)

## **Mechanical Data**

- Case: SMA
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (3)
- Polarity: Cathode Band or Cathode Notch
- Weight: 0.064 grams (Approximate)



Top View

Bottom View

## Ordering Information (Note 3)

Part Number*	Case	Packaging
US1x-13-F	SMA	5,000/Tape & Reel

\*x = Device type, e.g. US1A-13-F.

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  - 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## **Marking Information**



US1x = Product Type Marking Code, ex: US1A )|| = Manufacturers' Code Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 4 for 2014) WW = Week Code (01 to 53)



#### Maximum Ratings (@T<sub>A</sub> = +25°C unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.									
Characteristic	Symbol	US1A	US1B	US1D	US1G	US1J	US1K	US1M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 4)	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T <sub>T</sub> = +75°C	lo				1.0				А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>				30				А

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Terminal	$R_{\theta JT}$	30	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C

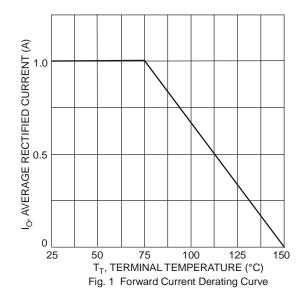
#### Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

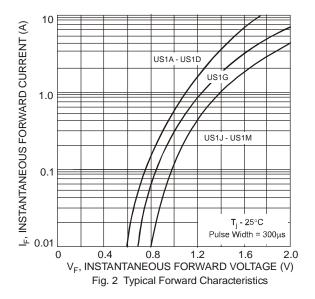
Characteristic		Symbol	US1A	US1B	US1D	US1G	US1J	US1K	US1M	Unit
Forward Voltage Drop	@ I <sub>F</sub> = 1.0A	V <sub>FM</sub>		1.0		1.3		1.7		V
Peak Reverse Current at Rated DC Blocking Voltage (Note 4)	@ T <sub>A</sub> = +25°C @ T <sub>A</sub> = +100°C	I <sub>RM</sub>				5.0 100				μA
Reverse Recovery Time (Note 5)		t <sub>rr</sub>		5	0			75		ns
Typical Total Capacitance (Note 6)		CT		2	0			10		pF

Notes:

4. Short duration pulse test used to minimize self-heating effect.

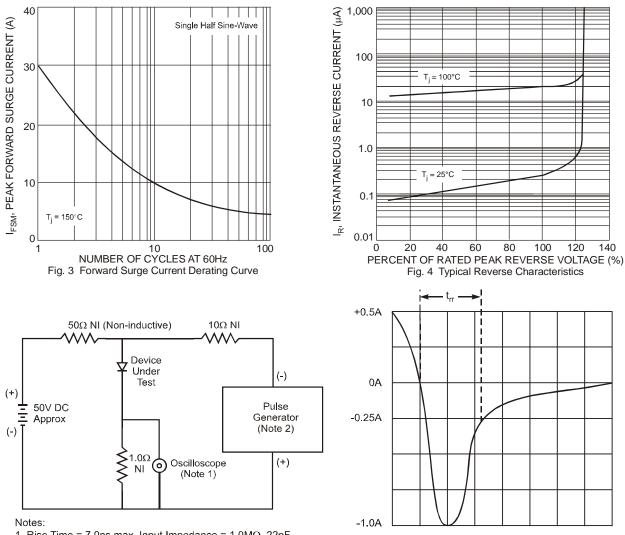
5. Measured with  $I_F$  = 0.5A,  $I_R$  = 1.0A,  $I_{rr}$  = 0.25A. See Figure 5. 6. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.







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1. Rise Time = 7.0ns max. Input Impedance =  $1.0M\Omega$ , 22pF. 2. Rise Time = 10ns max. Input Impedance =  $50\Omega$ .

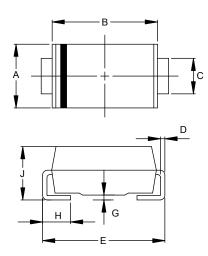
Set time base for 50/100 ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit



## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SMA						
Dim	Min	Max				
Α	2.29	2.92				
В	4.00	4.60				
С	1.27	1.63				
D	0.15	0.31				
E	4.80	5.59				
G	0.05	0.20				
Н	0.76	1.52				
J	1.96	2.40				
All Dimensions in mm						

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Dimensions	Value (in mm)
С	4.00
G	1.50
Х	2.50
X1	6.50
Y	1.70

#### US1A - US1M Document number: DS16008 Rev. 11 - 2

SMA



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